

# isc N-Channel MOSFET Transistor

# **IXTH200N10T**

#### • FEATURES

- · Drain Source Voltage-
  - : V<sub>DSS</sub>= 100V(Min)
- · Static Drain-Source On-Resistance
  - :  $R_{DS(on)} = 5.5 \text{m} \Omega \text{ (Max)}$
- · Fast Switching
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



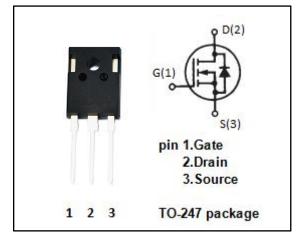
- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- · AC and DC Motor Drives
- · Robotics and Servo Controls

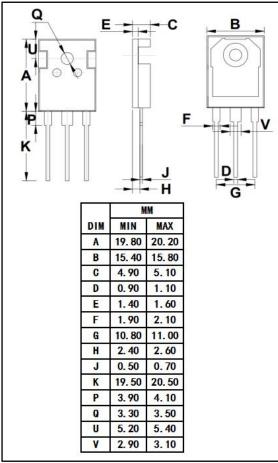
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	100	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±30	V
I <sub>D</sub>	Drain Current-Continuous	200	А
I <sub>DM</sub>	Drain Current-Single Plused	500	А
$P_D$	Total Dissipation @T <sub>C</sub> =25°C	550	W
Tj	Max. Operating Junction Temperature -55~175		$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55~175	${\mathbb C}$

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT				
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	0.27	°C/W				







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### • ELECTRICAL CHARACTERISTICS

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT		
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> =250μA	100			V		
$V_{\text{GS(th)}}$	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =250uA	2.5		4.5	V		
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> = 50A			5.5	mΩ		
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0			±200	nA		
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =100V; V <sub>GS</sub> = 0 V <sub>DS</sub> =100V; V <sub>GS</sub> = 0;T <sub>J</sub> =150°C			5 250	μА		
V <sub>SD</sub>	Diode Forward On-voltage	I <sub>F</sub> = 50A;V <sub>GS</sub> = 0			1	V		

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